

Date: Mar 04, 2022

PCN No#: 030422-1

PCN Title: MCC Introduces Auto-Assembly Process for SMA6J Series.

Dear Customer:

This is an announcement of change(s) to products that are currently being offered by Micro Commercial Components Corp(MCC) .We request that you acknowledge receipt of this notification within 30 days of the date of this PCN. Please refer to the implementation date of this change as it is stated in the attached PCN form. Please contact your local sales representative to acknowledge receipt of this PCN.

If you have any questions about PCN's products, please contact your local sales representative.

Sincerely,

MCC PCN Team



## **PRODUCT CHANGE NOTICE**

Notification Date	Implementation Date	Change Type	Classification	PCN No				
Mar 04, 2022	Jun 04, 2022	Auto-Assembly Process	Major	030422-1				
TITLE								
MCC Introduces Auto-A	ssembly Process For SMA	J Series.						
	D	ESCRIPTION OF CHANGE						
This PCN is being issued to notify customers that in order to assure continuity of supply, MCC added auto assembly line(Located in Yangzhou) for SMA6J Series. MCC has qualified the auto assembly line. Full electrical characterization and high reliability testing has been completed to ensure there is no change to device functionality or electrical specifications in the datasheet.								
IMPACT								
No change in datashee Table A: Appearance co	t electrical parameters and   omparison	product performance.						
		PRODUCTS AFFECTED						
See Table B & Table C for the products affected.								
WEB LINKS								
Terms And Conditions: https://www.mccsemi.com/Home/TermsAndConditions								
For More Information	for More Information Contact: https://www.mccsemi.com/Contact/Index							
Products:	Products: https://www.mccsemi.com/ProductCategories							
		DISCLAIMER						
Unless a MCC Sales representative is contacted in writing within 30 days of the posting of this notice, all changes described in this announcement are considered approved.								







Table B - List of affected products for industrial series						
SMA6J5.0A-TP	SMA6J5.0CA-TP	SMA6J13A-TP	SMA6J13CA-TP	SMA6J28A-TP	SMA6J28CA-TP	
SMA6J6.0A-TP	SMA6J6.0CA-TP	SMA6J14A-TP	SMA6J14CA-TP	SMA6J30A-TP	SMA6J30CA-TP	
SMA6J6.5A-TP	SMA6J6.5CA-TP	SMA6J15A-TP	SMA6J15CA-TP	SMA6J33A-TP	SMA6J33CA-TP	
SMA6J7.0A-TP	SMA6J7.0CA-TP	SMA6J16A-TP	SMA6J16CA-TP	SMA6J36A-TP	SMA6J36CA-TP	
SMA6J7.5A-TP	SMA6J7.5CA-TP	SMA6J17A-TP	SMA6J17CA-TP	SMA6J40A-TP	SMA6J40CA-TP	
SMA6J8.0A-TP	SMA6J8.0CA-TP	SMA6J18A-TP	SMA6J18CA-TP	SMA6J43A-TP	SMA6J43CA-TP	
SMA6J8.5A-TP	SMA6J8.5CA-TP	SMA6J19A-TP	SMA6J19CA-TP	SMA6J45A-TP	SMA6J45CA-TP	
SMA6J9.0A-TP	SMA6J9.0CA-TP	SMA6J20A-TP	SMA6J20CA-TP	SMA6J48A-TP	SMA6J48CA-TP	
SMA6J10A-TP	SMA6J10CA-TP	SMA6J22A-TP	SMA6J22CA-TP	SMA6J51A-TP	SMA6J51CA-TP	
SMA6J11A-TP	SMA6J11CA-TP	SMA6J24A-TP	SMA6J24CA-TP	SMA6J54A-TP	SMA6J54CA-TP	
SMA6J12A-TP	SMA6J12CA-TP	SMA6J26A-TP	SMA6J26CA-TP	SMA6J58A-TP	SMA6J58CA-TP	

Table C - List of affected products for automotive series							
SMA6J13AHE3-TP	SMA6J13CAHE3-TP	SMA6J19AHE3-TP	SMA6J19CAHE3-TP	SMA6J30AHE3-TP	SMA6J30CAHE3-TP		
SMA6J14AHE3-TP	SMA6J14CAHE3-TP	SMA6J20AHE3-TP	SMA6J20CAHE3-TP	SMA6J33AHE3-TP	SMA6J33CAHE3-TP		
SMA6J15AHE3-TP	SMA6J15CAHE3-TP	SMA6J22AHE3-TP	SMA6J22CAHE3-TP	SMA6J36AHE3-TP	SMA6J36CAHE3-TP		
SMA6J16AHE3-TP	SMA6J16CAHE3-TP	SMA6J24AHE3-TP	SMA6J24CAHE3-TP	SMA6J40AHE3-TP	SMA6J40CAHE3-TP		
SMA6J17AHE3-TP	SMA6J17CAHE3-TP	SMA6J26AHE3-TP	SMA6J26CAHE3-TP				
SMA6J18AHE3-TP	SMA6J18CAHE3-TP	SMA6J28AHE3-TP	SMA6J28CAHE3-TP				

Micro Commercial Components Corp. AECQ101 Discrete Device Reliability Test Report									
		urface Mount Transient			abii				
Voltage Suppressor Diodes Package type: DO-214AC (SMA) MSL Level: 1		Rel test No:RA2021120065			General Sp	ecification:	AECQ101	Rev E	
		Part No:SMA6J18AHE3			Lot No:SM	A			
		Final Lead Finish: 100% Matte Sn		Lead frame: EYJ210195/EYJ210196/EYJ210197					
Manufactru	ring sit	e: Yangzhou, China	Chip Type: SMAJ18A70			Qualificatio	on Reliability	Date:	2022/1/15
AECQ101 Item	Test Item	Test name	Ref. Specification	Test Condition	Lot #	Sample size	Result Fail/Total	Result	Remark
A1	PC	Preconditioning	JEDEC/IPC J-STD-020	Performed on surface mount devices prior to TC, AC,	3	308*3	0/308*3	ACC	
A2	HAST	Highly Accelerated Stress	JESD22-A-113 JEDEC	H3TRB or HAST, and IOL. 130°C/85%RH, 80% rated VR(TVS:100%VRWM) or	3	77*3	0/77*3	ACC	
A2 alt	H3TRB	Test High Humidity High Temp.	JESD22-A-110 JEDEC	42V max, 96 hours 85°C/85%RH, 80% rated VR(TVS:100%VRWM) or	NA	NA	NA	NA	Equivalent substitute by HAST
A3	UHAST	Reverse Bias Unbiased HAST	JESD22-A-101 JEDEC	80V max, 1000 hours 130°C/85%RH, 96 hours	3	77*3	0/77*3	ACC	
A3 alt	AC	Autoclave	JESD22-A-118, or A101 JEDEC	Ta = 121°C, P= 15 PSIG, RH = 100%, 96 Hours	NA	NA	NA	NA	Equivalent substitute by UHAST
A4	TC	Temperature Cycling	JESD22-A-102 JEDEC	-55°C to +150°C, t(dwell>15 min), 1000 Cycles	3	77*3	0/77*3	ACC	
A4a	тснт	Temperature Cycling Hot Test	JESD22-A-104 Appendix 6 JEDEC JESD22-A-104 Appendix 6	125°C TEST after TC using PV-determined limits at hot, followed by decap and wire pull (Test C3 WBP) on all wires from 5 devices per appendix 6 for parts with internal bond wire sizes 5 mil diameter and less.(Samples may be a sub set of test A4).	NA	NA	NA	NA	Required for MOSFETs parts with internal bond wire sizes 5 mil diameter and less.
A4a alt	TCDT	TC Delamination Test	JEDEC JESD22-A-104 Appendix 6 J-STD-035	100% AM inspection after TC, followed by decap, inspection or wire pull (Test C3 WBS) on all wires from 5 parts per appendix 6 for 5 highest delaminated parts. If AM shows no delaminating, no decap, inspection and wire pull is required.	NA	NA	NA	NA	
A5	IOL	Intermittent Operational Life	MIL-STD-750 Method 1037	Ta=25°C DeltaTj=100°C, t(on)=t(off)= 2 min, 15000 Cycles;	NA	NA	NA	NA	
A5 alt	PTC	Power Temperature Cycling	JEDEC JESD22-A-105	Perform PTC if TJ 100°C cannot be achieved with IOL.	NA	NA	NA	NA	
B1	HTRB	High Temperature Reverse Bias	MILSTD750-1 method M1038A	Tj= max, V=100% rated VR(TVS:100%VRWM), 1000 Hrs	3	77*3	0/77*3	ACC	
B1a	ACBV	AC Blocking Voltage	MIL-STD-750-1 M1040 Test condition A	Tj= max, AC=100% rated VR, 1000 Hrs	NA	NA	NA	NA	Required for Thyristors only.
B1b	SSOP	Steady State Operational	MIL-STD-750-1 M1038 condition B (Zeners)	1000 hours at rated IZ max, TA to rated TJ	NA	NA	NA	NA	Required for Voltage Regulators (Zeners) only.
B2	HTGB	High Temperature Gate Bias	JEDEC JESD22-A-108	Tj= max, Vgs=100%, 1000 Hrs	NA	NA	NA	NA	Required for MOS & IGBT parts only
C1	DPA	Destructive Physical Analysis	AEC Q101-004 Section 4	Choose 2 pcs for DPA after H3TRB and TC respectively	1	4	0/4	ACC	
C2 C3	PD WBP	Physical Dimension Wire Bond Pull Strength	JEDEC JESD22-B-100 MIL-STD-750-2 Method 2037 for Au and Al wire	/	NA NA	NA NA	NA NA	NA NA	Refer to the initial procedure data
			AEC Q006 for Cu wire AEC Q101-003						Keler to the mitial procedure data
C4 C5	WBS DS	Wire Bond Shear Strength Die Shear	JESD22 B116 MIL-STD-750-2	/	NA	NA	NA	NA	-
C6	TS	Terminal Strength	Method 2017 MIL-STD-750-2	/	NA	NA	NA	NA	Evaluate lead integrity of through-
		-	Method 2036 JEDEC	/					hole leaded parts only. Not required for laser etched
C7	RTS	Resistance to Solvents	JESD22-B-107 JEDEC JESD22-A-	/	NA	NA	NA	NA	parts or parts with no marking.
C8 C9	RSH TR	Resistance to Solder Heat Thermal Resistance	111 (SMD),or B-106 (PTH) JEDEC JESD24-3, 24-4,24-6 as	260(+5,-0)°C,10s	1 NA	30 NA	0/30 NA	ACC NA	Refer to the initial procedure data
C10	SD	Solderability	appropriate JEDEC J-STD-002	/ 245℃±5℃.3s	1	10	0/10	ACC	*
C11	WG	Whisker Growth Evaluation	AEC-Q005	/	NA	NA	NA	NA	For whisker requirements. Test to b done on a family basis (plating metallization, lead configuration).
C12	CA	Constant Acceleration	MIL-STD-750-2 Method 2006	/	NA	NA	NA	NA	
C13	VVF	Vibration Variable Frequency	JEDEC JESD2-B-103	/	NA	NA	NA	NA	Items C12 through C15 are sequential tests for hermetic
C14	MS	Mechanical Shock	JEDEC JESD22-B-104	/	NA	NA	NA	NA	packages.
C15	HER	Hermeticity	JEDEC JESD22-A-109	/	NA	NA	NA	NA	
D1	DI	Dielectric Integrity	AEC Q101-004 Section 3	/	NA	NA	NA	NA	Power MOS & IGBT only.
EO	EV	External Visual	JEDEC JESD22-B101	Device construction, marking, and workmanship	All	All	0/ALL	ACC	
E1	TEST	Pre and post stress electrical test	Device specification	/	All	All	0/ALL	ACC	
E2	PV	Parametric Verification	Device specification	Tested to device specification requirements	1	25	0/25	ACC	
E3	ESDH	ESD HBM Characterization	AEC Q101-001	100pF,1500Ω, ±2KV	NA	NA	NA	NA	For ESD capable devices only.
E4	ESDC	ESD CDM Characterization	AEC Q101-005	±500V	NA	NA	NA	NA	For ESD capable devices only.
E5	UIS	Unclamped Inductive Switching	AEC Q101-004 Section 2		NA	NA	NA	NA	Power MOS and internally clamped IGBTs only.
E6	SC	Short Circuit Characterization	AEC Q101-006		NA	NA	NA	NA	For smart power parts only.
Remark:	1.*: S 2.Defi Test	iolder-ability Test no nee nition of Test Failure Aft failures are defined as de ①. Devices not meating t ②. Devices not remaining and 5 times the initial va ③. Any device exhibiting	ed to test electricity, just f er Stressing: vices exhibiting any of the fo the electrical test limits defin g within ± 20% of the initial r lue for all others) after comp	llowing criteria: ed in the device specification. eading of each test (with the exception of leaka; etion of environmental testing. Tolutable to the environmental test.	I	1	I	1	
			Prepared By: Date:	Jiawen Li 2022/1/15		Approv	ved By: te:	Xiaojun H 2022/1/1	